

27C512A

512K (64K x 8) CMOS EPROM

FEATURES

- · High speed performance
- · CMOS Technology for low power consumption
 - 25 mA Active current
 - 30 µA Standby current
- · Factory programming available
- Auto-insertion-compatible plastic packages
- Auto ID aids automated programming
- High speed express programming algorithm
- Organized 64K x 8: JEDEC standard pinouts
 - 28-pin Dual-in-line package
 - 32-pin PLCC Package
- 28-pin SOIC package
- Tape and reel
- Data Retention > 200 years
- · Available for the following temperature ranges
 - 0°C to +70°C - Commercial:
 - -40°C to +85°C - Industrial:
 - Automotive: -40°C to +125°C

DESCRIPTION

The Microchip Technology Inc. 27C512A is a CMOS 512K bit electrically Programmable Read Only Memory (EPROM). The device is organized into 64K words by 8 bits (64K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 90 ns. This very high speed device allows the most sophisticated microprocessors to run at full speed without the need for WAIT states. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape or reel packaging is also available for PLCC or SOIC packages.

PACKAGE TYPES PLCC A7 A15 A15 A14 A14 A13 AF A8 Α5 28 A9 A4 A11 27C512A A3 NC A2 OE/Vpp A1 24 A10 23 CE A0 07 NC 06 004 00 N % 00 **DIP/SOIC** 28 3 Vcc 27 3 A14 A15 A12 🖵 Α7 26 🗔 A13 A6 _ 25 A5 24 🗁 A9 23 - A11 22 - OE/Vpp 27C512A AЗ 21 - A10 20 - CE A2 _

A1 ___ 9

00 ___ 11

A0 _____10

01 _ 12 02 _ 13

Vss -14

19 3 07

16 3 04

15 - 03

18 17 3 05

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1.0 ELECTRICAL CHARACTERISTICS

1.1 <u>Maximum Ratings*</u>

Vcc and input voltages w.r.t. Vss -0.6V to +7.25V

VPP voltage w.r.t. VSS during	
programming	0.6V to +14V
Voltage on A9 w.r.t. Vss	0.6V to +13.5V
Output voltage w.r.t. Vss	0.6V to Vcc +1.0V
Storage temperature	65°C to +150°C
Ambient temp. with power applied	65°C to +125°C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A15	Address Inputs
CE	Chip Enable
OE/Vpp	Output Enable/Programming Voltage
00 - 07	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connec- tion
NU	Not Used; No External Connection is Allowed

			Com	= +5V ±10 mercial: strial: nded (Aut	0% omotive):	Taml	Tamb = 0° C to +70°C Tamb = -40°C to +85°C Tamb = -40°C to +125°C		
Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions		
Input Voltages	all	Logic "1" Logic "0"	Vih Vil	2.0 -0.5	Vcc+1 0.8	V V			
Input Leakage	all		ILI	-10	10	μΑ	VIN = 0 to VCC		
Output Voltages	all	Logic "1" Logic "0"	Voh Vol	2.4	0.45	V V	IOH = - 400 μA IOL = 2.1 mA		
Output Leakage	all	—	Ilo	-10	10	μΑ	VOUT = 0V to VCC		
Input Capacitance	all	—	CIN	_	6	pF	VIN = 0V; Tamb = 25°C; f = 1 MHz		
Output Capacitance	all	_	Соит	—	12	pF	Vout = 0V; Tamb = 25° C; f = 1 MHz		
Power Supply Current, Active	C I, E	TTL input TTL input	ICC ICC		25 35	mA mA	VCC = 5.5V f = 1 MHz; OE/VPP = CE = VIL; IOUT = 0 mA; VIL = -0.1 to 0.8V; VIH = 2.0 to VCC; Note 1		
Power Supply Current, Standby	C I, E all	TTL input TTL input CMOS input	ICC(S)TLL ICC(S)TLL ICC(S)CMOS		1 2 30	mA mA μA	CE = Vcc±0.2V		

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

* Parts: C=Commercial Temperature Range; I, E=Industrial and Extended Temperature Ranges

Note 1: Typical active current increases .75 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

	AC Testing Waveform: Output Load: Input Rise and Fall Times: Ambient Temperature:					$VIH = 2.4V$ and $VIL = .45V$; $VOH = 2.0V$ and $VOL = 0.8$ 1 TTL Load + 100 pF10 nsCommercial:Industrial:Tamb = $-40^{\circ}C$ to $+85^{\circ}C$ Extended (Automotive):					
		27C5	12-90*	27C5 ²	12-10*	27C5	, 12-12	27C512-15			
Parameter	Sym	Min	Max	Min	Max	Min	Мах	Min	Мах	Units	Conditions
Address to Output Delay	tACC		90	_	100		120	_	150	ns	$\overline{CE} = \overline{OE}/$ VPP = VIL
CE to Output Delay	tCE		90	_	100		120	_	150	ns	OE/VPP = Vil
OE to Output Delay	tOE	_	40	_	40	_	50	_	60	ns	$\overline{CE} = VIL$
OE to Output High Impedance	tOFF	0	35	0	35	0	40	0	45	ns	
Output Hold from Address, CE or OE/ VPP, whichever occurred first	tон	0		0		0		0		ns	

*90/10 AC Testing Waveforms: VIH = 3.0V and VIL = 0V; VOH = 1.5V and VOL = 1.5V Output Load: 1 TTL Load + 30 pF

FIGURE 1-1: READ WAVEFORMS

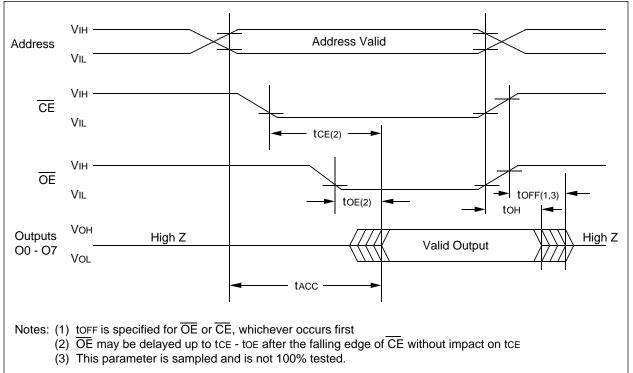


TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

	$\begin{array}{l} \mbox{Ambient Temperature: Tamb} = 25^{\circ}\mbox{C} \pm 5^{\circ}\mbox{C} \\ \mbox{Vcc} = 6.5\mbox{V} \pm 0.25\mbox{V}, \end{tabular} \overline{\mbox{OE}/\mbox{VPP}} = \mbox{VH} = 13.0\mbox{V} \pm 0.25\mbox{V} \end{array}$										
Parameter	Status	Status Symbol Min. Max. Units Conditions (Se									
Input Voltages	Logic "1"	Vін	2.0	Vcc+1	V						
	Logic "0"	VIL	-0.1	0.8	V						
Input Leakage	—	L	-10	10	μA	VIN = 0V to VCC					
Output Voltages	Logic "1"	Vон	2.4		V	ІОН = -400 μА					
	Logic "0"	Vol		0.45	V	IOL = 2.1 mA					
Vcc Current, program & verify	—	ICC2	_	35	mA	CE = VIL					
OE/VPP Current, program	_	IPP2		25	mA						
A9 Product Identification		Vid	11.5	12.5	V						

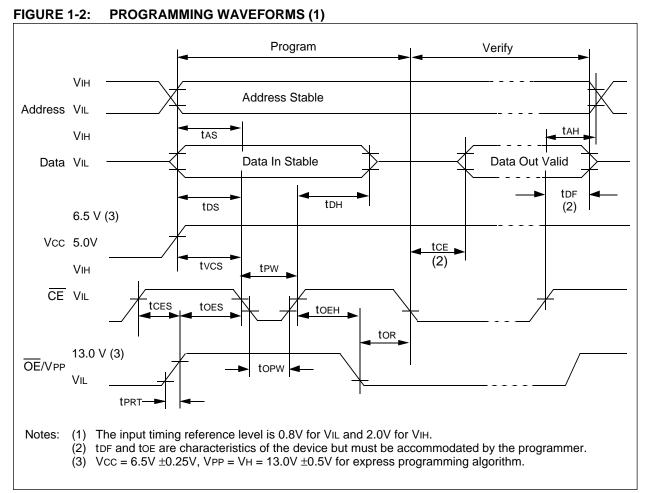
Note 1: VCC must be applied simultaneously or before VPP voltage on \overline{OE} /VPP and removed simultaneously or after the VPP voltage on \overline{OE} /VPP.

TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit ModesAC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V Ambient Temperature: 25°C ±5°C VCC = 6.5V ± 0.25V, OE/VPP = VH = 13.0V ± 0.25 V									
Parameter		Symbol	Min.	Max.	Units	Remarks			
Address Set-Up Time		tAS	2	_	μs				
Data Set-Up Time		tDS	2	—	μs				
Data Hold Time		tDH	2	—	μs				
Address Hold Time		tAH	0	—	μs				
Float Delay (2)		tDF	0	130	ns				
Vcc Set-Up Time		tvcs	2	_	μs				
Program Pulse Width (1)		tPW	95	105	μs	100 μs typical			
CE Set-Up Time		tCES	2	—	μs				
OE Set-Up Time		tOES	2	—	μs				
OE Hold Time		tOEH	2		μs				
OE Recovery Time		tOR	2	—	μs				
OE /VPP Rise Time During Programmir	ng	t PRT	50	_	ns				

Note 1: For express algorithm, initial programming width tolerance is 100 μs ±5%.

2: This parameter is only sampled and not 100% teted. Output float is defined as the point where data is no longer driven (see timing diagram).



Operation Mode	CE	OE/Vpp	A9	00 - 07
Read	VIL	VIL X Do		Dout
Program	VIL	Vн	VH X DIN	
Program Verify	VIL	VIL	Х	Dout
Program Inhibit	Vін	Vн	Х	High Z
Standby	Vін	Х	Х	High Z
Output Disable	VIL	Vін	Х	High Z
Identity	VIL	VIL	Vн	Identity Code

TABLE	E 1-6:	MODES

X = Don't Care

1.2 <u>Read Mode</u>

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- a) the CE pin is low to power up (enable) the chip
- b) the OE/VPP pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from \overline{CE} to output (tCE). Data is transferred to the output after a delay (tOE) from the falling edge of \overline{OE}/VPP .

1.3 Standby Mode

The standby mode is entered when the \overline{CE} pin is high, and the program mode is not identified.

When this conditions are met, the supply current will drop from 25 mA to 30 $\mu A.$

1.4 Output Enable OE/VPP

This multifunction pin eliminates bus connection in multiple bus microprocessor systems and the outputs go to high impedance when:

• the \overline{OE}/VPP pin is high (VIH).

When a VH input is applied to this pin, it supplies the programming voltage (VPP) to the device.

1.5 Erase Mode (UV Windowed Versions)

Windowed products offer the ability to erase the memory array. The memory matrix is erased to the all "1's" state as a result of being exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/ $\rm cm^2$ is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000 mW/cm² for approximately 40 minutes.

1.6 Programming Mode

The Express algorithm must be used for best results. It has been developed to improve programming yields and throughput times in a production environment. Up to 10 100-microsecond pulses are applied until the byte is verified. A flowchart of the Express algorithm is shown in Figure 1-3.

Programming takes place when:

- a) Vcc is brought to the proper voltage,
- b) \overline{OE}/VPP is brought to the proper VH level, and
- c) \overline{CE} line is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0 - A15 and the data to be programmed is presented to pins O0 - O7. When data and address are stable, a low going pulse on the \overline{CE} line programs that location.

1.7 <u>Verify</u>

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- a) Vcc is at the proper level,
- b) the \overline{OE}/VPP pin is low, and
- c) the \overline{CE} line is low.

1.8 Inhibit

When programming multiple devices in parallel with different data, only \overline{CE} needs to be under separate control to each device. By pulsing the \overline{CE} line low on a particular device, that device will be programmed; all other devices with \overline{CE} held high will not be programmed with the data (although address and data will be available on their input pins).

1.9 Identity Mode

In this mode specific data is output which identifies the manufacturer as Microchip Technology Inc. and the device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The \overline{CE} and \overline{OE}/VPP lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin 🗕	Input	Output								
Identity	A0	0 7	0 6	0 5	0 4	0 3	0 2	0 1	0 0	H e x
Manufacturer Device Type*	Vi∟ ViH	0 1	0 0	1 0	0 0	1 1	0 1	0 0	1 0	29 0D

* Code subject to change

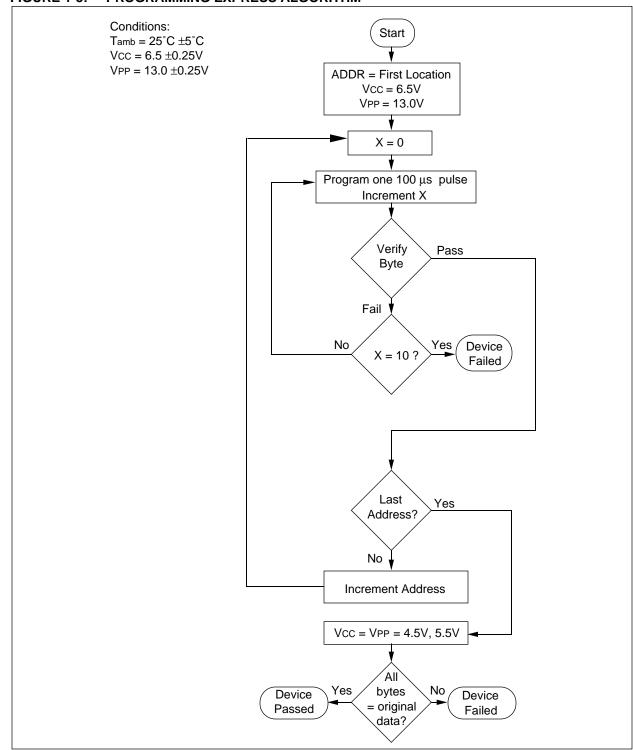


FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM

NOTES:

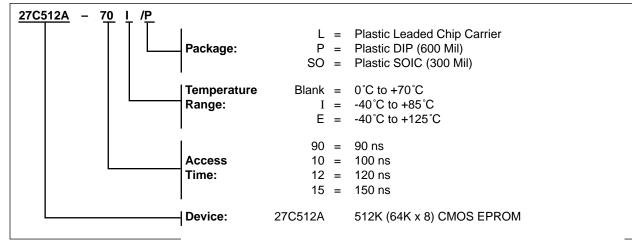
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NOTES:

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27C512A Product Identification System

To order or to obtain information (e.g., on pricing or delivery),, please use listed part numbers, and refer to factory or listed sales offices.



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- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the PICmicro microcontroller in a manner outside the operating specifications contained in the data sheet. The person doing so may be engaged in theft of intellectual property.
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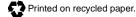
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